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# Quantum Transport FS 2015

## Superconducting Tunnel Junctions -

### Exercise 2 - 5.5.2015

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#### Problem 1 - tunnel junction made from aluminum

Superconducting tunnel junction can be prepared by the successive evaporation of two aluminum layers, with an intermediate oxidation step, that creates a thin insulating  $\text{Al}_2\text{O}_3$  layer on top of the first layer and acts as a tunnel barrier between the two superconductors. Explain how you would design an aluminum tunnel junction (with respect to area  $A$  and insulator thickness  $d$ ) depending on which ratio of  $E_C/E_J$  you want to realize.

Hint: The charging energy  $E_C$  is determined by the area  $A$  and the oxide thickness  $d$  (dielectric constant of  $\text{Al}_2\text{O}_3$ : 9.34). You can estimate the Josephson energy  $E_J$  from the Ambegaokar-Baratoff relation. The number of channels can be estimated as  $A/\lambda_F^2$ , the transparency per channel  $\tau \approx \exp(-2d\sqrt{2mU}/\hbar)$  with the barrier height  $U = 1.2\text{eV}$  for  $\text{Al}_2\text{O}_3$ .

#### Problem 2 - overdamped Josephson Junction

Consider the RCSJ model in the strongly overdamped case ( $Q \ll 1$ ): Calculate the I-V characteristics for this situation. Start from the usual differential equation

$$\ddot{\phi} + \dot{\phi}/Q + \sin \phi = I/I_c$$

Neglect the first term, and solve the remaining equation by separation of the variables  $\phi$  and  $\tau$ . Averaging over the phase can be done by integration from 0 to  $2\pi$ .